

TA2024B

STEREO 15W (4 Ω) CLASS-T^M DIGITAL AUDIO AMPLIFIER USING DIGITAL POWER PROCESSING^M TECHNOLOGY

Technical Information

Revision 1.1 - March 2005

GENERAL DESCRIPTION

The TA2024B is a 15W/ch continuous average two-channel Class-T Digital Audio Power Amplifier IC using Tripath's proprietary Digital Power Processing™ technology. Class-T amplifiers offer both the audio fidelity of Class-AB and the power efficiency of Class-D amplifiers.

APPLICATIONS

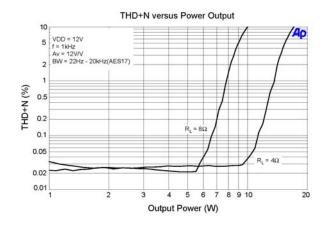
- Computer/PC Multimedia
- DVD Players
- Cable Set-Top Products
- Televisions
- Video CD Players
- Battery Powered Systems

BENEFITS

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- Fully integrated solution with FETs
- Easier to design-in than Class-D
- Reduced system cost with no heat sink
- Dramatically improves efficiency versus Class-AR
- Signal fidelity equal to high quality linear amplifiers
- High dynamic range compatible with digital media such as CD, DVD, and Internet audio

TYPICAL PERFORMANCE



FEATURES

- Class-T architecture
- Single Supply Operation
- "Audiophile" Quality Sound
 - ightarrow~ 0.03% THD+N @ 9W, 4 Ω
 - \triangleright 0.10% IHF-IM @ 1W, 4Ω
 - > 11W @ 4Ω, 0.1% THD+N
 - > 6W @ 8Ω, 0.1% THD+N
- High Power
 - 15W @ 4Ω, 10% THD+N
 - > 10W @ 8Ω, 10% THD+N
- > High Efficiency
 - > 81% @ 15W, 4Ω
 - > 90% @ 10W, 8Ω
- Dynamic Range = 98 dB
- Mute and Sleep inputs
- > Turn-on & turn-off pop suppression
- Over-current protection
- Over-temperature protection
- Bridged outputs
- > 36-pin Power SOP package



ABSOLUTE MAXIMUM RATINGS (Note 1)

SYMBOL	PARAMETER	Value	UNITS
V_{DD}	Supply Voltage	16	V
V5	Input Section Supply Voltage	6.0	V
SLEEP	SLEEP Input Voltage	-0.3 to 6.0	V
MUTE	MUTE Input Voltage	-0.3 to V5+0.3	V
T _{STORE}	Storage Temperature Range	-40 to 150	°C
T _A	Operating Free-air Temperature Range	0 to 70	°C
TJ	Junction Temperature	150	°C

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur.

Note 2: See Power Dissipation Derating in the Applications Information section.

OPERATING CONDITIONS (Note 4)

SYMBOL	PARAMETER	MIN.	TYP.	MAX.	UNITS
V_{DD}	Supply Voltage	8.5	12	13.2	V
V _{IH}	High-level Input Voltage (MUTE, SLEEP)	3.5			V
V _{IL}	Low-level Input Voltage (MUTE, SLEEP)			1	V

Note 3: Recommended Operating Conditions indicate conditions for which the device is functional. See Electrical Characteristics for guaranteed specific performance limits.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNITS
θις	Junction-to-case Thermal Resistance	2.5	°C/W
θја	Junction-to-ambient Thermal Resistance (still air)	50	°C/W

ELECTRICAL CHARACTERISTICS

See Test/Application Circuit. Unless otherwise specified, V_{DD} = 12V, f = 1kHz, Measurement Bandwidth = 22kHz, R_L = 4Ω , T_A = 25 °C, Package heat slug soldered to 2.8 square-inch PC pad.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Po	Output Power (Continuous Average/Channel)	$\begin{aligned} \text{THD+N} &= 0.1\% & \text{R}_{L} &= 4\Omega \\ \text{R}_{L} &= 8\Omega \\ \text{THD+N} &= 10\% & \text{R}_{L} &= 4\Omega \end{aligned}$	9 5.5 12 8	11 6 15 10		W W W
I _{DD.MUTE}	Mute Supply Current	$R_L = 8\Omega$	0	5.5	7	mA
I _{DD, SLEEP}	Sleep Supply Current	SLEEP = V _{IH}		0.25	2	mA
Iq	Quiescent Current	V _{IN} = 0 V		61	75	mA
THD + N	Total Harmonic Distortion Plus Noise	P ₀ = 9W/Channel		0.03		%
IHF-IM	IHF Intermodulation Distortion	19kHz, 20kHz, 1:1 (IHF)		0.10	0.5	%
SNR	Signal-to-Noise Ratio	A-Weighted, $P_{OUT} = 15W$, $R_L = 4\Omega$		98		dB
CS	Channel Separation	f = 1 kHz 20 Hz < f < 20 kHz	50	85 60		dB dB
PSRR	Power Supply Rejection Ratio	VDD = 9V to 13.2V Vripple = 100mVrms, f=1kHz	65	75 65		dB dB
η	Power Efficiency	P_{OUT} = 10W/Channel, R_L = 8 Ω		90		%
V _{OFFSET}	Output Offset Voltage	No Load, MUTE = Logic Low		50	150	V
V _{OH}	High-level output voltage (FAULT & OVERLOAD)		3.5			V
V _{OL}	Low-level output voltage (FAULT & OVERLOAD)				1	V
e _{OUT}	Output Noise Voltage	A-Weighted, input AC grounded		100		μV

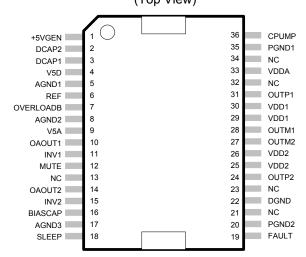
Note: Minimum and maximum limits are guaranteed but may not be 100% tested.

PIN DESCRIPTION

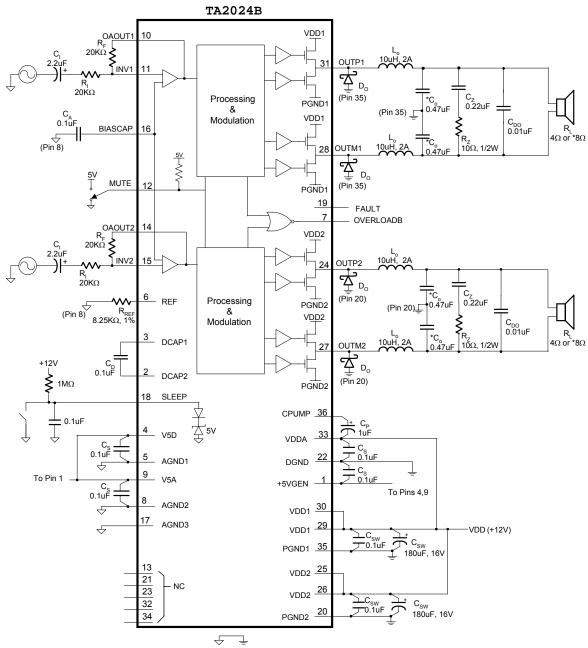
Pin	Function	Description
2, 3	DCAP2, DCAP1	Charge pump switching pins. DCAP1 (pin 3) is a free running 300kHz square
		wave between VDDA and DGND (12Vpp nominal). DCAP2 (pin 2) is level shifted
		10 volts above DCAP1 (pin 3) with the same amplitude (12Vpp nominal),
4.0	\/ED \/EA	frequency, and phase as DCAP1.
4, 9	V5D, V5A	Digital 5VDC, Analog 5VDC
5, 8,	AGND1, AGND2,	Analog Ground
17	AGND3	Laternal aufores and the second discrete A OV/DO
6 7	REF	Internal reference voltage; approximately 1.0 VDC.
	OVERLOADB	A logic low output indicates the input signal has overloaded the amplifier.
10, 14	OAOUT1, OAOUT2	Input stage output pins.
11, 15	INV1, INV2	Single-ended inputs. Inputs are a "virtual" ground of an inverting opamp with approximately 2.4VDC bias.
12	MUTE	When set to logic high, both amplifiers are muted and in idle mode. When low
		(grounded), both amplifiers are fully operational. If left floating, the device stays in
		the mute mode. This pin should be tied to GND if not used.
16	BIASCAP	Input stage bias voltage (approximately 2.4VDC).
18	SLEEP	When set to logic high, device goes into low power mode. If not used, this pin
		should be grounded
19	FAULT	A logic high output indicates thermal overload, or an output is shorted to ground, or another output.
20, 35	PGND2, PGND1	Power Grounds (high current)
22	DGND	Digital Ground. Connect to AGND locally (near the TA2024B).
24, 27;	OUTP2 & OUTM2;	Bridged output pairs
31, 28	OUTP1 & OUTM1	
25, 26,	VDD2, VDD2	Supply pins for high current H-bridges, nominally 12VDC.
29, 30	VDD1, VDD1	
13, 21,	NC	Not connected. Not bonded internally.
23, 32,		
34		
33	VDDA	Analog 12VDC
36	CPUMP	Charge pump output (nominally 10V above VDDA)
1	5VGEN	Regulated 5VDC source used to supply power to the input section (pins 4 and 9).

TA2024B PINOUT

36-pin Power SOP Package (Top View)



APPLICATION / TEST CIRCUIT



Note: Analog and Digital/Power Grounds must be connected locally at the TA2024B

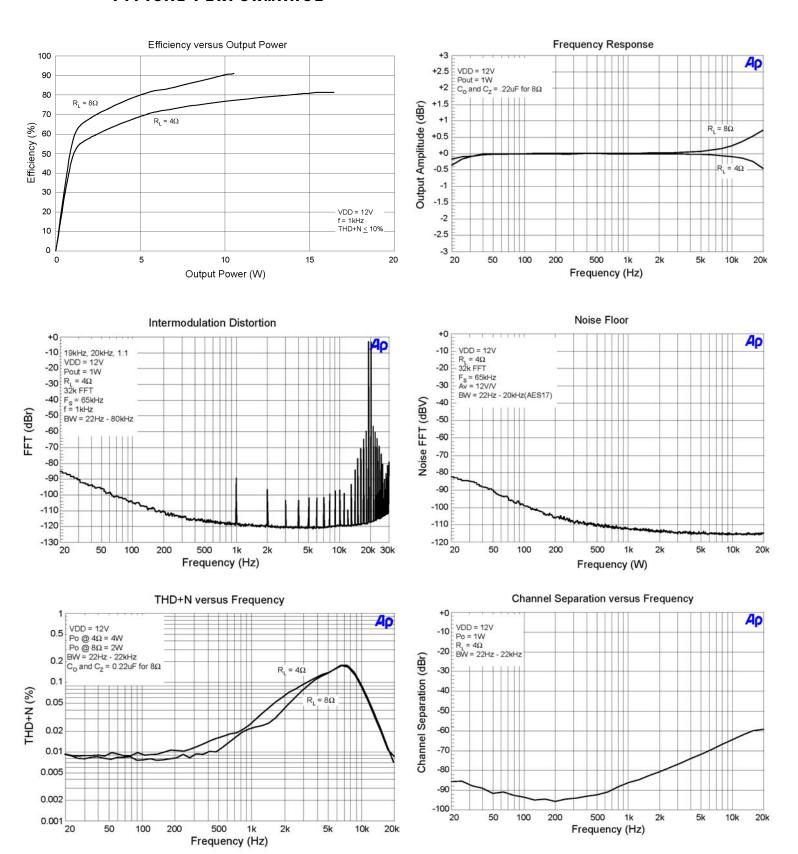
- Analog Ground
- □ Digital/Power Ground
 All Diodes Motorola MBRS130T3
 - * Use C_o = 0.22 μ F for 8 Ohm loads

$\textbf{EXTERNAL} \quad \textbf{COMPONENTS} \quad \textbf{DESCRIPTION} \quad \text{(Refer to the Application/Test Circuit)}$

Components Description

biased at the BIASCAP voltage (approximately 2.4VDC). R _F Feedback resistor to set AC gain in conjunction with R _i ; A _v = 12(R _F /R _i). Please refer to the Amplifier Gain paragraph in the Application Information section. C ₁ AC input coupling capacitor which, in conjunction with R _i , forms a highpass filter at f _c = 1/(2πR _C). R _{REF} Bias resistor. Locate close to pin 6 (REF) and ground at pin 8 (AGND2). C _A BIASCAP decoupling capacitor. Should be located close to pin 16. C _D Charge pump input capacitor. This capacitor should be connected directly between pins 2 (DCAP2) and 3 (DCAP1) and located physically close to the TA2024B. C _P Charge pump output capacitor that enables efficient high side gate drive for the internal H-bridges. To maximize performance, this capacitor should be connected directly between pin 36 (CPUMP) and pin 33 (VDDA). Please observe the polarity shown in the Application/Test Circuit. C _S Supphy decoupling for the low current power supply pins. For optimum performance these components should be located close to the pin and returned to their respective ground as shown in the Application/Test Circuit. C _{SW} Supphy decoupling for the high current, high frequency H-Bridge supply pins. These components must be located as close to the device as possible to minimize supply overshoot and maximize device reliability. Both the high frequency bypassing (0.1uF) and bulk capacitor (180uF) should have good high frequency performance including low ESR and low ESL. Panasonic HFQ or FC capacitors are ideal for the bulk capacitor.	Components	Description
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$ \begin{array}{c} C_{l} & AC \ input \ coupling \ capacitor \ which, in \ conjunction \ with \ R_{l}, forms \ a highpass \ filter \ at \ t_{c} = 1/(2\pi R_{C_{l}}) \\ & Bias \ resistor. \ Locate \ close to \ pin \ 6 \ (REF) \ and \ ground \ at \ pin \ 8 \ (AGND2). \\ & BIASCAP \ decoupling \ capacitor. \ Should \ be \ located \ close to \ pin \ 16. \\ & C_{D} & Charge \ pump \ input \ capacitor. \ This \ capacitor \ should \ be \ connected \ directly \ between \ pin \ 3 \ (DCAP1) \ and \ located \ physically \ close to \ the \ TA2024B. \\ & C_{P} & Charge \ pump \ output \ capacitor \ that \ enables \ efficient \ high \ side \ gate \ drive \ for \ the \ internal \ H-bridges. \ To \ maximize \ performance, this \ capacitor \ should \ be \ connected \ directly \ between \ pin \ 36 \ (CPUMP) \ and \ pin \ 33 \ (VDDA). \ Please \ observe \ the \ polarity \ shown in \ the \ Application/\ Test \ Circuit. \\ & C_{S} & Supply \ decoupling \ for \ the \ low \ current \ power \ supply \ pins. \ For \ optimum \ performance \ these \ components \ should \ be \ located \ close \ to \ the \ pin \ and \ returned \ to \ their \ respective \ ground \ as \ shown \ in \ the \ Application/Test \ Circuit. \\ & C_{SW} & Supply \ decoupling \ for \ the \ low \ current \ power \ supply \ pins. \ For \ optimum \ performance \ these \ components \ must \ be \ located \ as \ close \ to \ the \ device \ as \ possible \ to \ minimize \ supply \ overshoot \ and \ maximize \ device \ reliability. \ Both \ the \ high \ frequency \ performance \ including \ low \ ESR \ and \ low \ ESL. \ Panasonic \ HFQ \ or \ FC \ capacitors \ are \ ideal for \ the \ bulk \ capacitor. \\ & C_{Z} & Zobel \ Capacitor. \\ & D_{O} & Schottky \ diodes \ that \ minimize \ undershoots \ of \ the \ output \ filter \ under \ both \ no \ load \ conditions \ or \ with \ real \ world \ loads, \ including \ loudspeakers \ which \ usually \ exhibit \ a \ rising \ impedance \ with \ frequency. \\ & D_{O} & Schottky \ diodes \ $	R _F	Feedback resistor to set AC gain in conjunction with R_i ; $A_v = 12(R_F/R_i)$. Please refer
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ground during switching transitions. For maximum effectiveness, these diodes must be located close to the output pins and returned to their respective PGND. Please see Application/Test Circuit for ground return pin. Lo Output inductor, which in conjunction with C_O and C_{DO} , demodulates (filters) the switching waveform into an audio signal. Forms a second order filter with a cutoff frequency of $f_C = 1/(2\pi\sqrt{L_OC_{TOT}})$ and a quality factor of $Q = R_LC_{TOT}/2\sqrt{L_OC_{TOT}}$ where $C_{TOT} = C_O \parallel 2 * C_{DO}$. Co Output capacitor. CDO Differential Output Capacitor. Differential noise decoupling for reduction of conducted emissions. Must be located near chassis exit point for maximum	R _z	frequencies. The combination of R_Z and C_Z minimizes peaking of the output filter under both no load conditions or with real world loads, including loudspeakers which usually exhibit a rising impedance with frequency.
switching waveform into an audio signal. Forms a second order filter with a cutoff frequency of $f_C = 1/(2\pi\sqrt{L_{_{O}}C_{_{TOT}}})$ and a quality factor of $Q = R_{_{L}}C_{_{TOT}}/2\sqrt{L_{_{O}}C_{_{TOT}}} \text{ where } C_{TOT} = C_{O} \parallel 2 * C_{DO}.$ $C_{O} \qquad \text{Output capacitor.}$ $C_{DO} \qquad \text{Differential Output Capacitor. Differential noise decoupling for reduction of conducted emissions. Must be located near chassis exit point for maximum}$	Do	ground during switching transitions. For maximum effectiveness, these diodes must be located close to the output pins and returned to their respective PGND. Please see Application/Test Circuit for ground return pin.
C _O Output capacitor. C _{DO} Differential Output Capacitor. Differential noise decoupling for reduction of conducted emissions. Must be located near chassis exit point for maximum	Lo	switching waveform into an audio signal. Forms a second order filter with a cutoff frequency of $f_{\rm C}=1/(2\pi\sqrt{{\rm L}_{\rm O}{\rm C}_{\rm TOT}})$ and a quality factor of
C _{DO} Differential Output Capacitor. Differential noise decoupling for reduction of conducted emissions. Must be located near chassis exit point for maximum	Co	<u> </u>
effectiveness.		Differential Output Capacitor. Differential noise decoupling for reduction of

TYPICAL PERFORMANCE



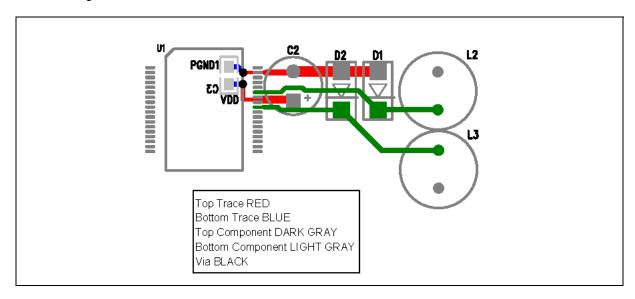
APPLICATION INFORMATION

Layout Recommendations

The TA2024B is a power (high current) amplifier that operates at relatively high switching frequencies. The outputs of the amplifier switch between the supply voltage and ground at high speeds while driving high currents. This high-frequency digital signal is passed through an LC low-pass filter to recover the amplified audio signal. Since the amplifier must drive the inductive LC output filter and speaker loads, the amplifier outputs can be pulled above the supply voltage and below ground by the energy in the output inductance. To avoid subjecting the TA2024B to potentially damaging voltage stress, it is critical to have a good printed circuit board layout. It is recommended that Tripath's layout and application circuit be used for all applications and only be deviated from after careful analysis of the effects of any changes. Please contact Tripath Technology for further information regarding reference design material regarding the TA2024B.

Output Stage layout Considerations and Component Selection Criteria

Proper PCB layout and component selection is a major step in designing a reliable TA2024B power amplifier. The supply pins require proper decoupling with correctly chosen components to achieve optimal reliability. The output pins need proper protection to keep the outputs from going below ground.



The above layout shows ideal component placement and routing for channel 1 (the same design criteria applies to channel 2). This shows that C3, a 0.1uF surface mount 0805 capacitor, should be the first component placed and must decouple VDD1 (pins 29 and 30) directly to PGND1 (pin35). C2, a low ESR, electrolytic capacitor, should also decouple VDD1 directly to PGND1. Both C2 and C3 may decouple VDD1 to a ground plane, but it is critical that the return path to the PGND1 pin of the TA2024B, whether it is a ground plane or a trace, be a short and direct low impedance path. Effectively decoupling VDD will shunt any power supply trace length inductance.

The diodes and inductors shown are for channel 1's outputs. D1 and L2 connect to the OUTP1 pin and D2 and L3 connect to the OUTM1 pin of the TA2024B. Each output must have a Schottky or Ultra Fast Recovery diode placed near the TA2024B, preferably immediately after the decoupling capacitors and use short returns to PGND1. These low side diodes, D1 and D2, will prevent the outputs from going below ground. To be optimally effective they must have a short and direct return path to its proper ground pin (PGND1) of the TA2024B. This can be achieved with a ground plane or a trace.

The output inductors, L2 and L3, should be placed close to the TA2024B without compromising the locations of the closely placed supply decoupling capacitors and output diodes. The purpose

of placing the output inductors close to the TA2024B output pins is to reduce the trace length of the switching outputs. This will aid in reducing radiated emissions.

Please see the External Component Description section on page 6 for more details on the above-mentioned components. The Application/ Test Circuit refers to the low side diodes as D_O , The high side diodes as D_H , and both supply decoupling capacitors as C_{SW} .

TA2024B Amplifier Gain

The ideal gain of the TA2024B is set by the ratio of two external resistors, R_I and R_F , and is given by the following formula:

$$\frac{V_O}{V_I} = -12 \frac{R_F}{R_I}$$

where V_I is the input signal level and V_O is the differential output signal level across the speaker. Please note that V_O is 180° out of phase with V_I .

The ideal gain of the TA2024B is 12V/V, whereas typical values are: A_V = 11.5V/V for 4Ω and 11.7V/V for 8Ω .

Protection Circuits

The TA2024B is guarded against over-temperature and over-current conditions. When the device goes into an over-temperature or over-current state, the FAULT pin goes to a logic HIGH state indicating a fault condition. When this occurs, the amplifier is muted, all outputs are TRI-STATED, and will float to 1/2 of $V_{\rm DD}$.

Over-temperature Protection

An over-temperature fault occurs if the junction temperature of the part exceeds approximately 155°C. The thermal hysteresis of the part is approximately 45°C, therefore the fault will automatically clear when the junction temperature drops below 110°C.

Over-current Protection

An over-current fault occurs if more than approximately 7 amps of current flows from any of the amplifier output pins. This can occur if the speaker wires are shorted together or if one side of the speaker is shorted to ground. An over-current fault sets an internal latch that can only be cleared if the MUTE pin is toggled or if the part is powered down. Alternately, if the MUTE pin is connected to the FAULT pin, the HIGH output of the FAULT pin will toggle the MUTE pin and automatically reset the fault condition.

Overload

The OVERLOADB pin is a 5V logic output. When low, it indicates that the level of the input signal has overloaded the amplifier resulting in increased distortion at the output. The OVERLOADB signal can be used to control a distortion indicator light or LED through a simple buffer circuit, as the OVERLOADB cannot drive an LED directly.

Sleep Pin

The SLEEP pin is a 5V logic input that when pulled high (>3.5V) puts the part into a low quiescent current mode. This pin is internally clamped by a zener diode to approximately 6V thus allowing the pin to be pulled up through a large valued resistor (1meg Ω recommended) to V_{DD}. To disable SLEEP mode, the sleep pin should be grounded.

Fault Pin

The FAULT pin is a 5V logic output that indicates various fault conditions within the device. These conditions include: low supply voltage, low charge pump voltage, low 5V regulator voltage, over current at any output, and junction temperature greater than approximately 155°C. All faults except overcurrent all reset upon removal of the condition. The FAULT output is capable of directly driving an LED through a series $2k\Omega$ resistor. If the FAULT pin is connected directly to the MUTE input an automatic reset will occur in the event of an over-current condition.

Power Dissipation Derating

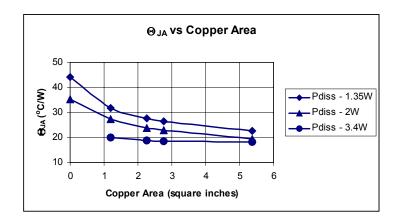
For operating at ambient temperatures above 25°C the device must be derated based on a 150°C maximum junction temperature, TJMAX as given by the following equation:

$$P_{DISS} = \frac{(T_{JMAX} - T_A)}{\theta_{JA}}$$

where...

PDISS = maximum power dissipation
TJMAX = maximum junction temperature of TA2024B
TA = operating ambient temperature
0JA = junction-to-ambient thermal resistance

Where θ_{JA} of the package is determined from the following graph:



In the above graph Copper Area is the size of the copper pad on the PC board to which the heat slug of the TA2024B is soldered. *The heat slug must be soldered to the PC Board* to increase the maximum power dissipation capability of the TA2024B package. Soldering will minimize the likelihood of an over-temperature fault occurring during continuous heavy load conditions. The vias used for connecting the heatslug to the copper area on the PCB should be 0.013" diameter.

Performance Measurements of the TA2024B

The TA2024B operates by generating a high frequency switching signal based on the audio input. This signal is sent through a low-pass filter (external to the Tripath amplifier) that recovers an amplified version of the audio input. The frequency of the switching pattern is spread spectrum and typically varies between 100kHz and 1.0MHz, which is well above the 20Hz – 20kHz audio band. The pattern itself does not alter or distort the audio input signal but it does introduce some inaudible components.

The measurements of certain performance parameters, particularly noise related specifications such as THD+N, are significantly affected by the design of the low-pass filter used on the output as well as the bandwidth setting of the measurement instrument used. Unless the filter has a very sharp roll-off just beyond the audio band or the bandwidth of the measurement instrument is limited, some of the inaudible noise components introduced by the Tripath amplifiers switching pattern will degrade the measurement.

One feature of the TA2024B is that it does not require large multi-pole filters to achieve excellent performance in listening tests, usually a more critical factor than performance measurements. Though using a multi-pole filter may remove high-frequency noise and improve THD+N type measurements (when they are made with wide-bandwidth measuring equipment), these same filters degrade frequency response. The TA2024B Evaluation Board uses the Test/Application Circuit in this data sheet, which has a simple two-pole output filter and excellent performance in listening tests. Measurements in this data sheet were taken using this same circuit with a limited bandwidth setting in the measurement instrument.

PACKAGE INFORMATION

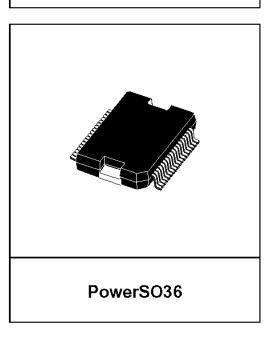
The package for the TA2024B is a 36-Lead Power Small Outline Package (PSOP), similar to JEDEC outline MO-166, variation AE. Tripath currently has two suppliers for this package. We recommend that the exposed copper heatslug width for the PCB design be at least 7.3mm wide to accommodate the heatslug width variation for each package.

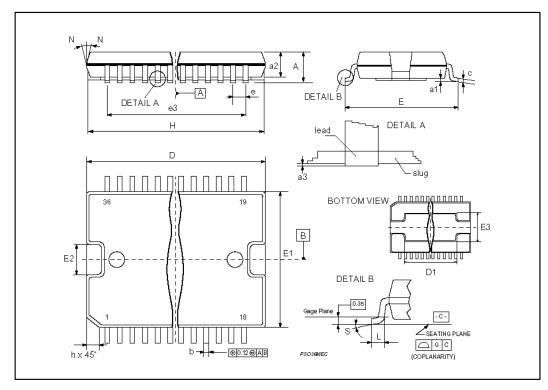
DIM.	mm			inch			
DIIVI.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
Α			3.60			0.141	
a1	0.10		0.30	0.004		0.012	
a2			3.30			0.130	
а3	0		0.10	0		0.004	
b	0.22		0.38	0.008		0.015	
С	0.23		0.32	0.009		0.012	
D (1)	15.80		16.00	0.622		0.630	
D1	9.40		9.80	0.370		0.385	
E	13.90		14.50	0.547		0.570	
е		0.65			0.025		
е3		11.05			0.435		
E1 (1)	10.90		11.10	0.429		0.437	
E2			2.90			0.114	
E3	5.80		6.20	0.228		0.244	
E4	2.90		3.20	0.114		0.126	
G	0		0.10	0		0.004	
Н	15.50		15.90	0.610		0.626	
h			1.10			0.043	
L	0.80		1.10	0.031		0.043	
N			10°(r	nax)	•		
S	8°(max.)						

(1): "D" and "E1" do not include mold flash or protrusions - Mold flash or protrusions shall not exceed 0.15mm (0.006 inch) - Critical dimensions are "a3", "E" and "G".

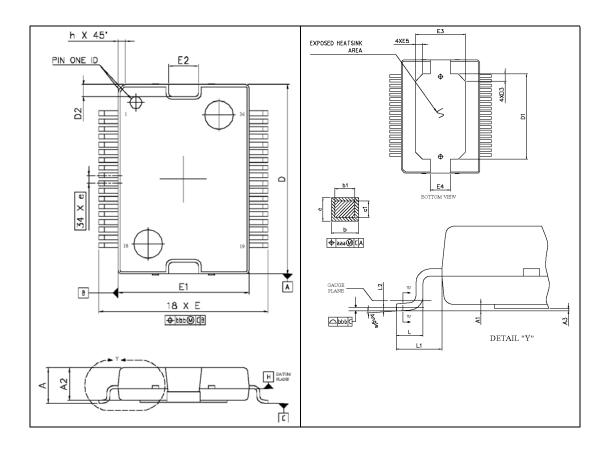
S 8°(max.)

OUTLINE AND MECHANICAL DATA





Outline and mechanical data for PSOP36



DIM	MIN	MAX	DIM	MIN	MAX	
Α	-	3.600	E1	11.00) BSC	
A1	0.100	-	E2	-	2.900	
A2	3.000	3.300	E3	6.300 7.300		
A3	0.025	0.152	E4	2.700 2.900		
D	15.90 BSC		E5	-	1.000	
D1	9.000	13.000	L	0.800 1.100		
D2	-	1.100	L1	1.60 REF		
D3	-	1.000	L2	0.350 BSC		
Е	14.200 BSC		All DIM measured in mm			

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